CMOS Low Voltage 2 Ω SPST Switches

ADG701/ADG702

FEATURES

1.8 V to 5.5 V single supply
2 Ω (typ) on resistance
Low on-resistance flatness
–3 dB bandwidth > 200 MHz
Rail-to-rail operation
Fast switching times:
t_{ON} 18 ns
t_{OFF} 12 ns
Typical power consumption < 0.01 µW
TTL/CMOS compatible

APPLICATIONS

Battery powered systems
Communication systems
Sample hold systems
Audio signal routing
Video switching
Mechanical reed relay replacement

GENERAL DESCRIPTION

The ADG701/ADG702 are monolithic CMOS SPST switches. These switches are designed on an advanced submicron process that provides low power dissipation yet high switching speed, low on resistance, and low leakage currents. In addition, −3 dB bandwidths of greater than 200 MHz can be achieved.

The ADG701/ADG702 can operate from a single 1.8 V to 5.5 V supply, making it ideal for use in battery-powered instruments and with the new generation of DACs and ADCs from Analog Devices.

Figure 1 shows that with a logic input of 1, the switch of the ADG701 is closed, while that of the ADG702 is open. Each switch conducts equally well in both directions when on.

The ADG701/ADG702 are available in 5-lead SOT-23, 6-lead SOT-23, and 8-lead MSOP packages.

FUNCTIONAL BLOCK DIAGRAM

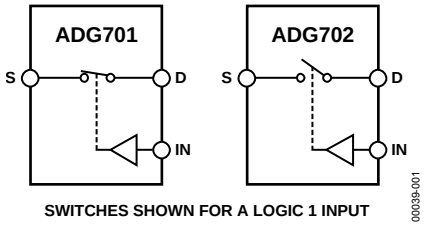

Figure 1.

PRODUCT HIGHLIGHTS

1. 1.8 V to 5.5 V single-supply operation. The ADG701/ADG702 offer high performance, including low on resistance and fast switching times, and are fully specified and guaranteed with 3 V and 5 V supply rails.
2. Very low R_{ON} (3 Ω max at 5 V, 5 Ω max at 3 V). At 1.8 V operation, R_{ON} is typically 40 Ω over the temperature range.
3. On resistance flatness $R_{FLAT(ON)}$ (1 Ω max).
4. −3 dB bandwidth > 200 MHz.
5. Low power dissipation. CMOS construction ensures low power dissipation.
6. Fast t_{ON}/t_{OFF}.
7. Tiny 5-lead SOT-23, 6-lead SOT-23, and 8-lead MSOP packages.

Rev. B

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700 **www.analog.com**
Fax: 781.326.8703

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REVISION HISTORY

6/04—Data Sheet Changed from Rev. A to Rev. B

Updated Format ..... Universal
Added 5-Lead SOT-23 Package ..... Universal
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8/98—Data Sheet Changed from Rev. 0 to Rev. A

SPECIFICATIONS

V_{DD} = 5 V ± 10%, GND = 0 V. Temperature range for B version is −40°C to +85°C, unless otherwise noted.

Table 1.

Parameter	B Version +25°C	B Version −40°C to +85°C	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 V to V_{DD}	V	
On Resistance (R_{ON})	2		Ω typ	V_S = 0 V to V_{DD}, I_S = −10 mA; Figure 11
	3	4	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)	0.5		Ω typ	V_S = 0 V to V_{DD}, I_S = −10 mA
		1.0	Ω max	
LEAKAGE CURRENTS				V_{DD} = 5.5 V
Source OFF Leakage, I_S (OFF)	±0.01		nA typ	V_S = 4.5 V/1 V, V_D = 1 V/4.5 V; Figure 12
	±0.25	±0.35	nA max	
Drain OFF Leakage, I_D (OFF)	±0.01		nA typ	V_S = 4.5 V/1 V, V_D = 1 V/4.5 V; Figure 12
	±0.25	±0.35	nA max	
Channel ON Leakage, I_D, I_S (ON)	±0.01		nA typ	V_S = V_D = 1 V, or 4.5 V; Figure 13
	±0.25	±0.35	nA max	
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.4	V min	
Input Low Voltage, V_{INL}		0.8	V max	
Input Current				
I_{INL} or I_{INH}	0.005		μA typ	V_{IN} = V_{INL} or V_{INH}
		±0.1	μA max	
DYNAMIC CHARACTERISTICS[1]				
t_{ON}	12		ns typ	R_L = 300 Ω , C_L = 35 pF
		18	ns max	V_S = 3 V; Figure 14
t_{OFF}	8		ns typ	R_L = 300 Ω , C_L = 35 pF
		12	ns max	V_S = 3 V; Figure 14
Charge Injection	5		pC typ	V_S = 2 V, R_S = 0 Ω , C_L = 1 nF; Figure 15
Off Isolation	−55		dB typ	R_L = 50 Ω , C_L = 5 pF, f = 10 MHz
	−75		dB typ	R_L = 50 Ω , C_L = 5 pF, f = 1 MHz; Figure 16
Bandwidth −3 dB	200		MHz typ	R_L = 50 Ω , C_L = 5 pF; Figure 17
C_S (OFF)	17		pF typ	
C_D (OFF)	17		pF typ	
C_D, C_S (ON)	38		pF typ	
POWER REQUIREMENTS				V_{DD} = 5.5 V
				Digital inputs = 0 V or 5 V
I_{DD}	0.001		μA typ	
		1.0	μA max	

[1] Guaranteed by design, not subject to production test.

V_{DD} = 3 V ±10%, GND = 0 V. Temperature range for B version is −40°C to +85°C, unless otherwise noted.

Table 2.

Parameter	B Version +25°C	B Version −40°C to +85°C	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 V to V_{DD}	V	
On Resistance (R_{ON})	3.5		Ω typ	V_S = 0 V to V_{DD}, I_S = −10 mA; Figure 11
	5	6	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)	1.5		Ω typ	V_S = 0 V to V_{DD}, I_S = −10 mA
LEAKAGE CURRENTS				V_{DD} = 3.3 V
Source OFF Leakage I_S(OFF)	±0.01		nA typ	V_S = 3 V/1 V, V_D = 1 V/3 V; Figure 12
	±0.25	±0.35	nA max	
Drain OFF Leakage I_D(OFF)	±0.01		nA typ	V_S = 3 V/1 V, V_D = 1 V/3 V; Figure 12
	±0.25	±0.35	nA max	
Channel ON Leakage I_D, I_S(ON)	±0.01		nA typ	V = V_D = 1 V, or 3 V; Figure 13
	±0.25	±0.35	nA max	
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.0	V min	
Input Low Voltage, V_{INL}		0.4	V max	
Input Current				
I_{INL} or I_{INH}	0.005		μA typ	V_{IN} = V_{INL} or V_{INH}
		±0.1	μA max	
DYNAMIC CHARACTERISTICS[1]				
t_{ON}	14		ns typ	R_L = 300 Ω , C_L = 35 pF
		20	ns max	V_S = 2 V, Figure 14
t_{OFF}	8		ns typ	R_L = 300 Ω , C_L = 35 pF
		13	ns max	V_S = 2 V, Figure 14
Charge Injection	4		pC typ	V_S = 1.5 V, RS = 0 Ω , C_L = 1 nF; Figure 15
Off Isolation	−55		dB typ	R_L = 50 Ω , C_L = 5 pF, f = 10 MHz
	−75		dB typ	R_L = 50 Ω , C_L = 5 pF, f = 1 MHz; Figure 16
Bandwidth −3 dB	200		MHz typ	R_L = 50 Ω , C_L = 5 pF; Figure 17
C_S (OFF)	17		pF typ	
C_D (OFF)	17		pF typ	
C_D, C_S (ON)	38		pF typ	
POWER REQUIREMENTS				V_{DD} = 3.3 V Digital Inputs = 0 V or 3 V
I_{DD}	0.001		μA typ	
		1.0	μA max	

[1] Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

T_A = +25°C, unless otherwise noted.

Table 3.

Parameter	Rating
V_{DD} to GND	−0.3 V to +7 V
Analog, Digital Inputs[1]	−0.3 V to V_{DD} +0.3 V or 30 mA, whichever occurs first
Continuous Current, S or D	30 mA
Peak Current, S or D	100 mA, pulsed at 1 ms, 10% duty cycle max
Operating Temperature Range	
Industrial (B Version)	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
MSOP Package, Power Dissipation	315 mW
θ_{JA} Thermal Impedance	206°C/W
θ_{JC} Thermal Impedance	44°C/W
SOT-23 Package, Power Dissipation	282 mW
θ_{JA} Thermal Impedance	229.6°C/W
θ_{JC} Thermal Impedance	91.99°C/W
Lead Temperature, Soldering	
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C
ESD	2 kV

[1] Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

Table 4. Truth Table

ADG701 In	ADG702 In	Switch Condition
0	1	OFF
1	0	ON

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

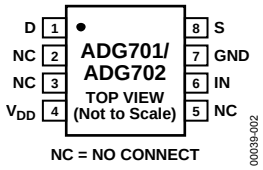

Figure 2. 8-Lead MSOP

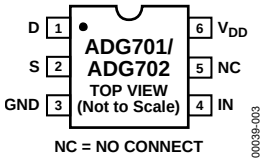

Figure 3. 6-Lead SOT-23

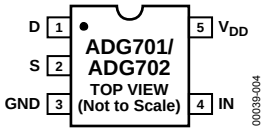

Figure 4. 5-Lead SOT-23

Table 5. Pin Descriptions

Term	Description
V_{DD}	Most positive power supply potential.
GND	Ground (0 V) Reference.
S	Source Terminal. May be an input or output.
D	Drain Terminal. May be an input or output.
IN	Logic Control Input.
R_{ON}	Ohmic resistance between D and S.
$R_{FLAT(ON)}$	Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.
I_S (OFF)	Source Leakage Current with the Switch OFF.
I_D (OFF)	Drain Leakage Current with the Switch OFF.
I_D, I_S (ON)	Channel Leakage Current with the Switch ON.
V_D (VS)	Analog Voltage on Terminals D and S.
C_S (OFF)	OFF Switch Source Capacitance.
C_D (OFF)	OFF Switch Drain Capacitance.
C_D, C_S (ON)	ON Switch Capacitance.
t_{ON}	Delay between applying the digital control input and the output switching on. See Figure 14.
t_{OFF}	Delay between applying the digital control input and the output switching off.
Off Isolation	A measure of unwanted signal coupling through an OFF switch.
Charge Injection	A measure of the glitch impulse transferred from the digital input to the analog output during switching.
Bandwidth	The frequency at which the output is attenuated by −3 dBs.
On Response	The frequency response of the ON switch.
On Loss	The voltage drop across the ON switch seen in Figure 10 as the number of dBs the signal is from 0 dB at very low frequencies.

TYPICAL PERFORMANCE CHARACTERISTICS

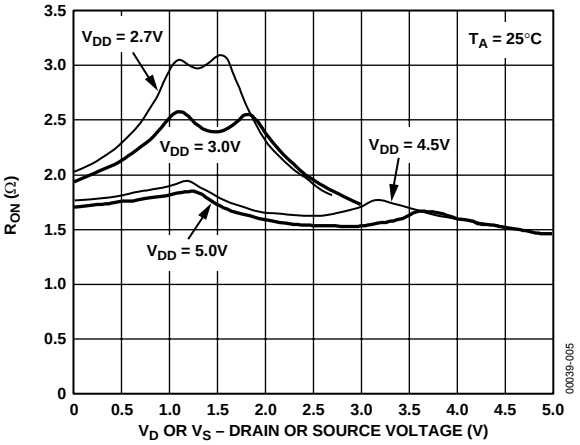

Figure 5. On Resistance as a Function of V_D (V_S) Single Supplies

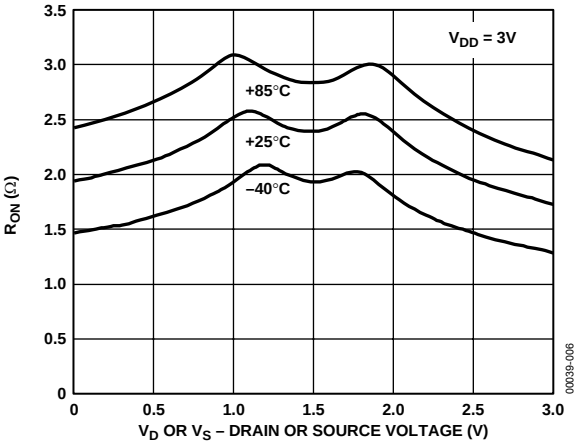

Figure 6. On Resistance as a Function of V_D (V_S) for Different Temperatures V_{DD} = 3 V

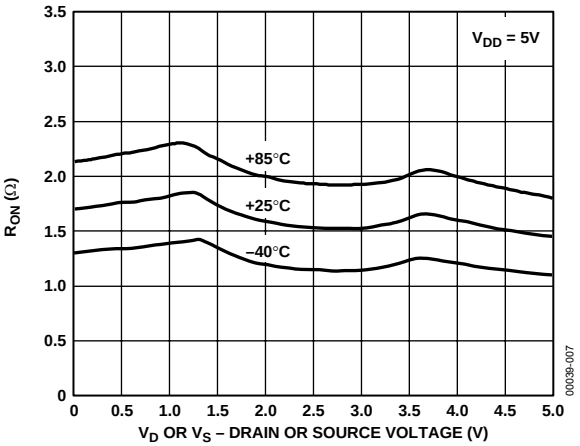

Figure 7. On Resistance as a Function of V_D (V_S) for Different Temperatures V_{DD} = 5 V

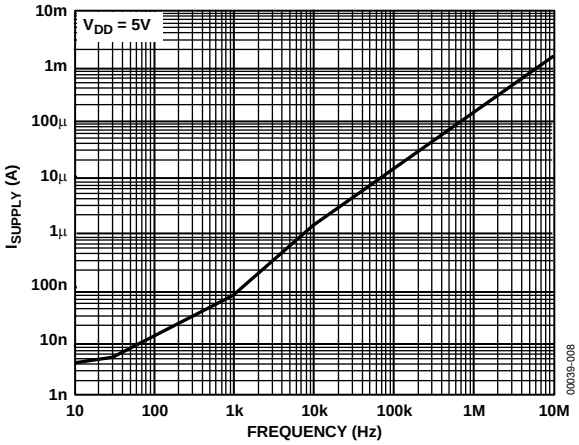

Figure 8. Supply Current vs. Input Switching Frequency

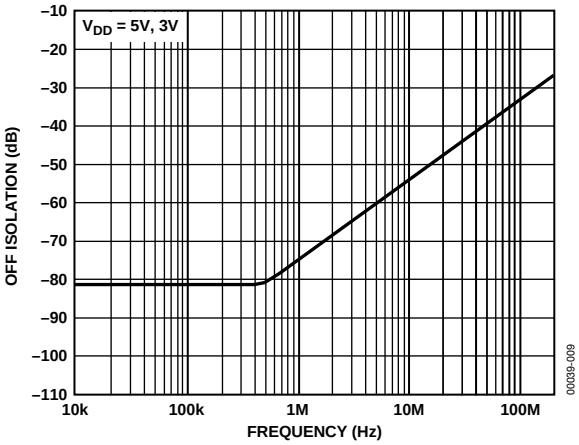

Figure 9. Off Isolation vs. Frequency

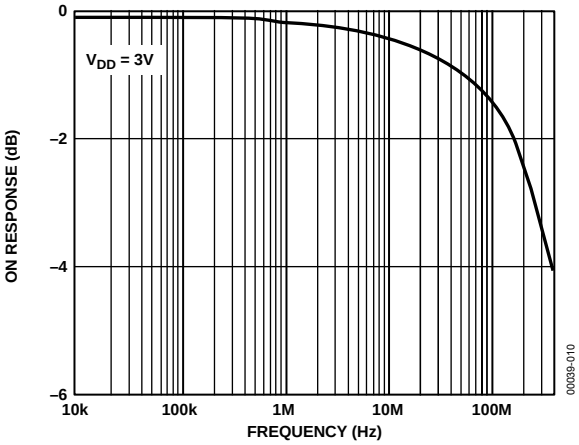

Figure 10. On Response vs. Frequency

TEST CIRCUITS

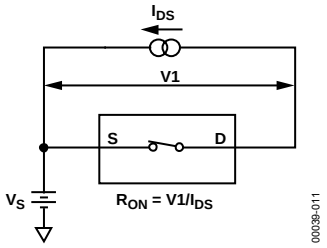

Figure 11. On Resistance

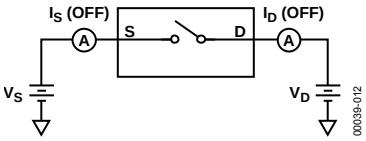

Figure 12. Off Leakage

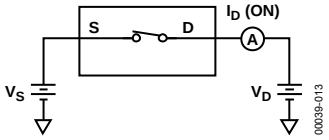

Figure 13. On Leakage

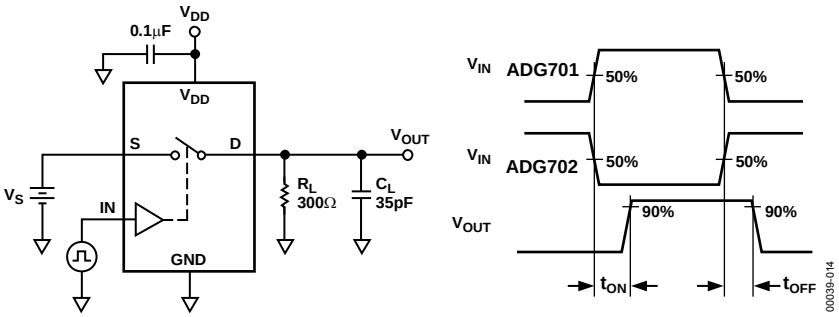

Figure 14. Switching Times

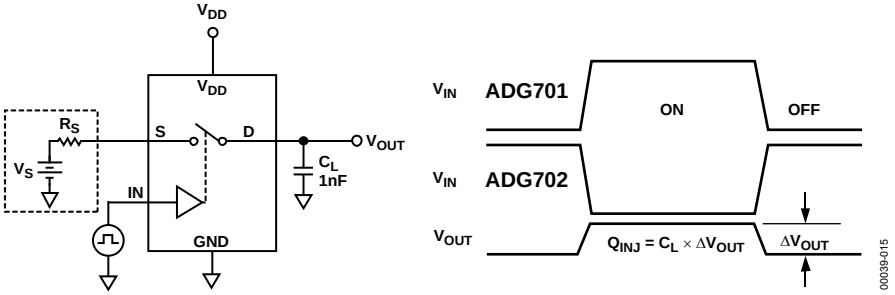

Figure 15. Charge Injection

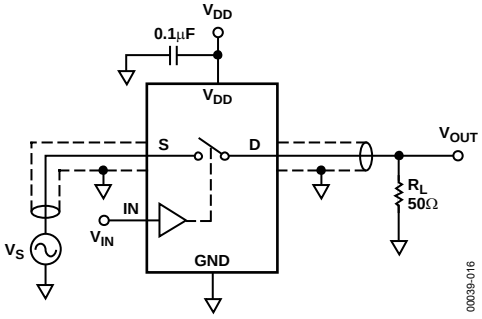

Figure 16. Off Isolation

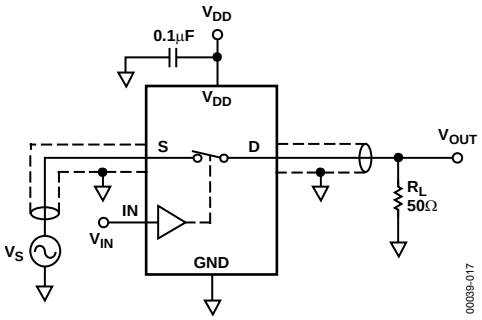

Figure 17. Bandwidth

APPLICATIONS INFORMATION

The ADG701/ADG702 belong to Analog Devices' new family of CMOS switches. This series of general-purpose switches have improved switching times, lower on resistance, higher bandwidth, low power consumption, and low leakage currents.

ADG701/ADG702 SUPPLY VOLTAGES

Functionality of the ADG701/ADG702 extends from 1.8 V to 5.5 V single supply, making the parts ideal for battery-powered instruments, where power efficiency and performance are important design parameters.

It is important to note that the supply voltage affects the input signal range, the on resistance, and the switching times of the part. The effects of the power supplies can be clearly seen in the Typical Performance Characteristics and the Specifications sections.

For V_{DD} = 1.8 V operation, R_{ON} is typically 40 Ω over the temperature range.

ON RESPONSE VS. FREQUENCY

Figure 18 illustrates the parasitic components that affect the ac performance of CMOS switches (a box surrounds the switch). Additional external capacitances further degrade some performance. These capacitances affect feedthrough, crosstalk, and system bandwidth.

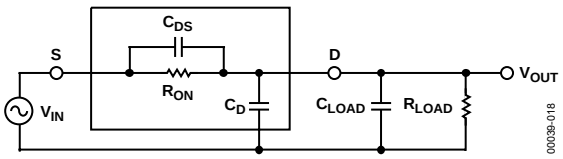

Figure 18. Switch Represented by Equivalent Parasitic Components

The transfer function that describes the equivalent diagram of the switch (Figure 18) is of the form (A)s shown below.

$$A(s) = R_T\left[\frac{s(R_{ON}C_{DS})+1}{s(R_{ON}C_TR_T)+1}\right]$$

Where $C_T = C_{LOAD} + C_D + C_{DS}$.

The signal transfer characteristic is dependent on the switch channel capacitance, C_{DS}. This capacitance creates a frequency zero in the numerator of the transfer function A(s). Because the switch on resistance is small, this zero usually occurs at high frequencies. The bandwidth is a function of the switch output capacitance combined with C_{DS} and the load capacitance. The frequency pole corresponding to these capacitances appears in the denominator of A(s).

The dominant effect of the output capacitance, C_D, causes the pole breakpoint frequency to occur first. In order to maximize bandwidth, a switch must have a low input and output capacitance and low on resistance. The on response versus frequency for the ADG701/ADG702 can be seen in Figure 10.

OFF ISOLATION

Off isolation is a measure of the input signal coupled through an off switch to the switch output. The capacitance, C_{DS}, couples the input signal to the output load, when the switch is off, as shown in Figure 19.

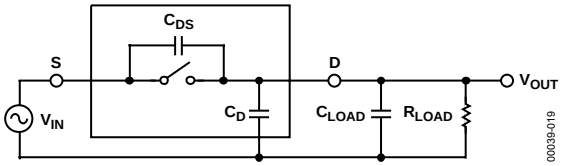

Figure 19. Off Isolation Is Affected by External Load Resistance and Capacitance

The larger the value of C_{DS}, the larger the values of feedthrough produced. Figure 9 illustrates the drop in off isolation as a function of frequency. From dc to roughly 1 MHz, the switch shows better than −75 dB isolation. Up to frequencies of 10 MHz, the off isolation remains better than −55 dB. As the frequency increases, more and more of the input signal is coupled through to the output. Off isolation can be maximized by choosing a switch with the smallest C_{DS} possible. The values of load resistance and capacitance also affect off isolation, as they contribute to the coefficients of the poles and zeros in the transfer function of the switch when open.

$$A(s) = R_T\left[\frac{s(R_{LOAD}C_{DS})+1}{s(R_{LOAD})(C_T)+1}\right]$$

OUTLINE DIMENSIONS

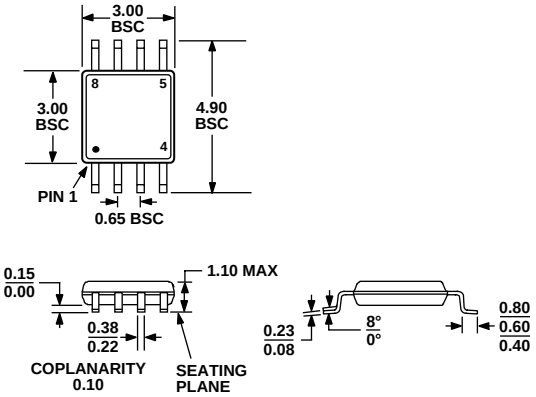

Figure 20. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)
Dimensions shown in millimeters

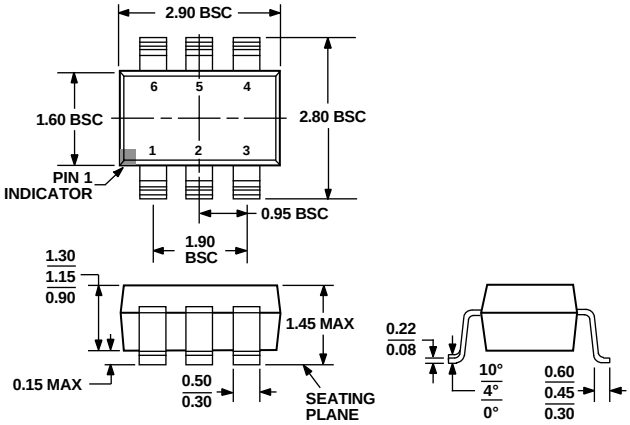

Figure 21. 6-Lead Plastic Surface Mount Package [SOT-23]
(RT-6)
Dimensions shown in inches and (millimeters)

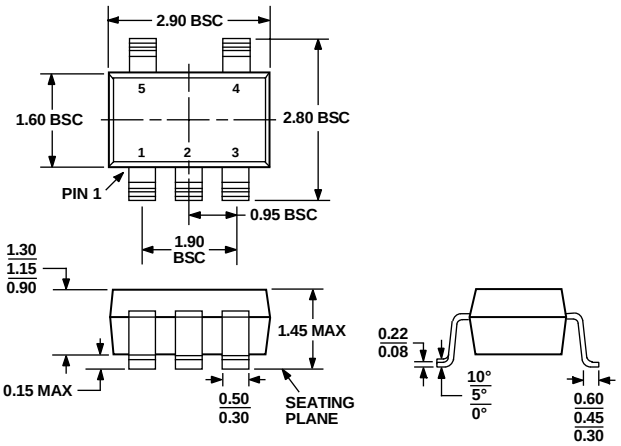

Figure 22. 5-Lead Plastic Surface Mount Package [SOT-23]
(RJ-5)
Dimensions shown in inches and (millimeters)

ORDERING GUIDE

Model	Temperature Range	Package Descriptions	Package Options	Brand[1]
ADG701BRJ-500RL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RJ-5	S3B
ADG701BRJ-REEL	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RJ-5	S3B
ADG701BRJ-REEL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RJ-5	S3B
ADG701BRM	−40°C to +85°C	MSOP (Small Outline)	RM-8	S3B
ADG701BRM-REEL	−40°C to +85°C	MSOP (Small Outline)	RM-8	S3B
ADG701BRM-REEL7	−40°C to +85°C	MSOP (Small Outline)	RM-8	S3B
ADG701BRT	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S3B
ADG701BRT-REEL	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S3B
ADG701BRT-REEL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S3B
ADG701BRTZ-REEL[2]	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S3B
ADG701BRTZ-REEL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S3B
ADG702BRJ-500RL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RJ-5	S4B
ADG702BRJ-REEL	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RJ-5	S4B
ADG702BRJ-REEL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RJ-5	S4B
ADG702BRM	−40°C to +85°C	MSOP (Small Outline)	RM-8	S4B
ADG702BRM-REEL	−40°C to +85°C	MSOP (Small Outline)	RM-8	S4B
ADG702BRM-REEL7	−40°C to +85°C	MSOP (Small Outline)	RM-8	S4B
ADG702BRT	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S4B
ADG702BRT-REEL	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S4B
ADG702BRT-REEL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S4B
ADG702BRTZ-REEL	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S4B
ADG702BRTZ-REEL7	−40°C to +85°C	SOT-23 (Plastic Surface Mount)	RT-6	S4B

[1] Brand = Due to package size limitations, these three characters represent the part number.
[2] Z = Pb-free part.

NOTES

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